

General purpose transistor (isolated transistor and diode)

US5L9

A 2SB1709 and a RB461F are housed independently in a TUMT5 package.

●Applications

DC / DC converter
Motor driver

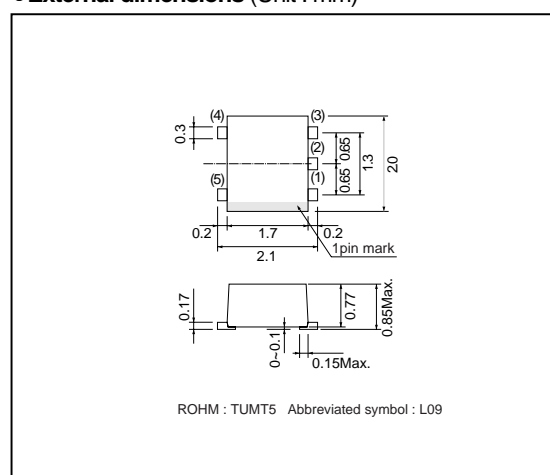
●Features

- 1) T_r : Low $V_{CE(sat)}$
Di : Low V_f
- 2) Small package

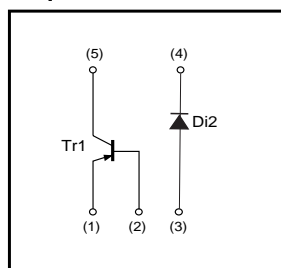
●Structure

Silicon epitaxial planar transistor
Schottky barrier diode

●External dimensions (Unit : mm)



●Equivalent circuit



●Packaging specifications

Type	US5L9
Package	TUMT5
Marking	L09
Code	TR
Basic ordering unit(pieces)	3000

Transistors

●Absolute maximum ratings (Ta=25°C)

Tr1

Parameter	Symbol	Limits	Unit
Collector-base voltage	V _{CB0}	-15	V
Collector-emitter voltage	V _{CEO}	-12	V
Emitter-base voltage	V _{EBO}	-6	V
Collector current	I _C	-1.5	A
	I _{CP}	-3	A *1
Power dissipation	P _C	0.7	W/ELEMENT *2
Junction temperature	T _J	150	°C
Range of storage temperature	T _{stg}	-40 to +125	°C

*1 Single pulse, P_w=1ms.

*2 Mounted on a 25mm×25mm×0.8mm CERAMIC SUBSTRATE.

Di2

Parameter	Symbol	Limits	Unit
Peak reverse voltage	V _{RM}	25	V
Reverse voltage (DC)	V _R	20	V
Average rectified forward current	I _F	700	mA
Forward current surge peak (60Hz, 1∞)	I _{FSM}	3	A
Power dissipation	P _D	0.5	W/ELEMENT *
Junction temperature	T _J	125	°C
Range of storage temperature	T _{stg}	-40 to +125	°C

* Mounted on a 25mm×25mm×0.8mm CERAMIC SUBSTRATE.

Tr1&Di2

Parameter	Symbol	Limits	Unit
Total power dissipation	P _D	0.4	W/TOTAL *2
		1.0	W/TOTAL *1

*1 Mounted on a 25mm×25mm×0.8mm CERAMIC SUBSTRATE.

*2 Each terminal mounted on a recommended land.

●Electrical characteristics (Ta=25°C)

Tr1

Parameter	Symbol	Min.	Typ.	Max.	Unit	Conditions
Collector-emitter breakdown voltage	BV _{CEO}	-12	-	-	V	I _C =-1mA
Collector-base breakdown voltage	BV _{CB0}	-15	-	-	V	I _C =-10μA
Emitter-base breakdown voltage	BV _{EBO}	-6	-	-	V	I _E =-10μA
Collector cut-off current	I _{CB0}	-	-	-100	nA	V _{CB} =-15V
Emitter cut-off current	I _{EBO}	-	-	-100	nA	V _{EB} =-6V
Collector-emitter saturation voltage	V _{CE(sat)}	-	-110	-200	mV	I _C =-500mA, I _B =-25mA
DC current gain	h _{FE}	270	-	680	-	V _{CE} =-2V, I _C =-200mA
Transition frequency	f _T	-	400	-	MHz	V _{CE} =-2V, I _E =200mA, f=100MHz
Collector output capacitance	C _{ob}	-	12	-	pF	V _{CB} =-10V, I _E =0mA, f=1MHz

Di2

Parameter	Symbol	Min.	Typ.	Max.	Unit	Conditions
Forward voltage	V _F	-	-	490	mV	I _F =700mA
Reverse current	I _R	-	-	200	μA	V _R =20V
Reverse recovery time	t _{rr}	-	9	-	nS	I _F =I _R =100mA, I _{rr} =0.1I _R

Transistors

●Electrical characteristic curves

Tr1

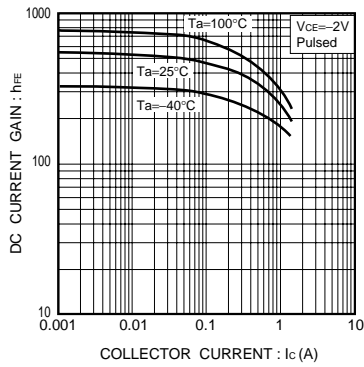


Fig.1 DC current gain vs. collector current

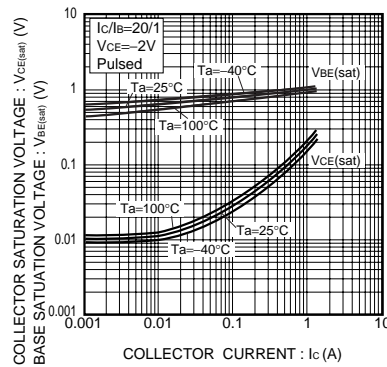


Fig.2 Base-emitter saturation voltage vs. collector current

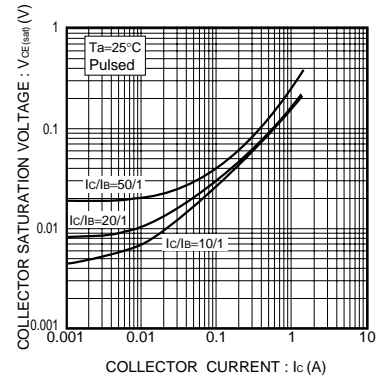


Fig.3 Collector-emitter saturation voltage vs. collector current

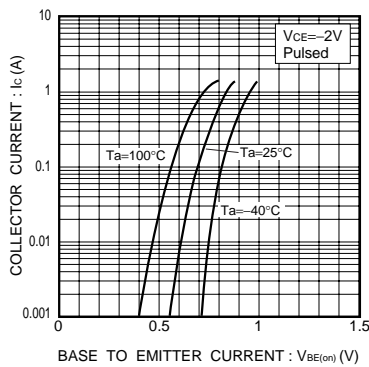


Fig.4 Grounded emitter propagation characteristics

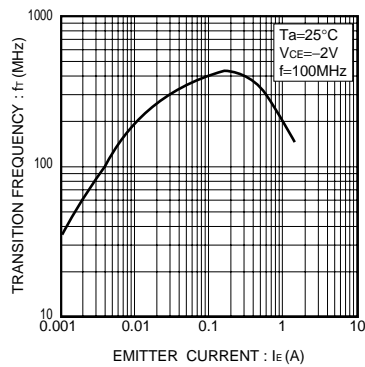


Fig.5 Gain bandwidth product vs. emitter current

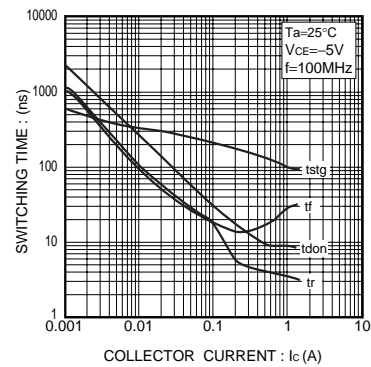


Fig.6 Switching time

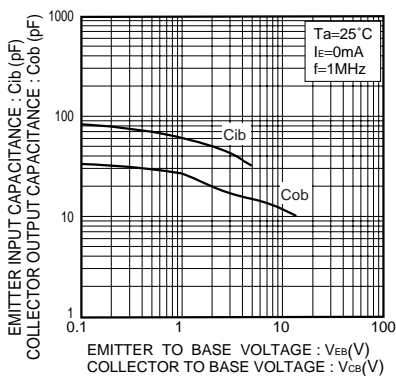


Fig.7 Collector output capacitance vs. collector-base voltage
Emitter input capacitance vs. emitter-base voltage

Transistors

Di2

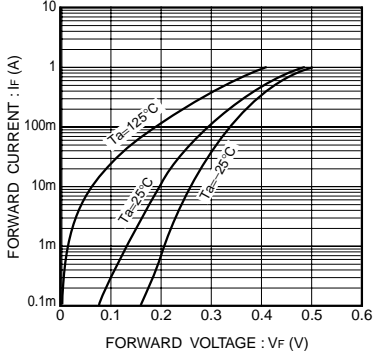


Fig.8 Forward characteristics

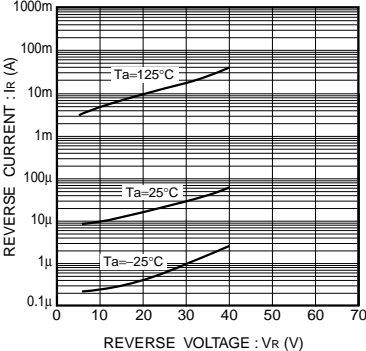


Fig.09 Reverse characteristics

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